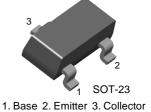


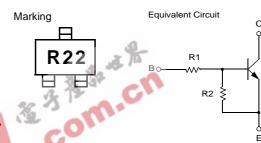
FJV3102R

Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit Built in bias Resistor (R_1 =10 $K\Omega$, R_2 =10 $K\Omega$)
- Complement to FJV4102R



Rev. A, July 2002



NPN Epitaxial Silicon Transistor

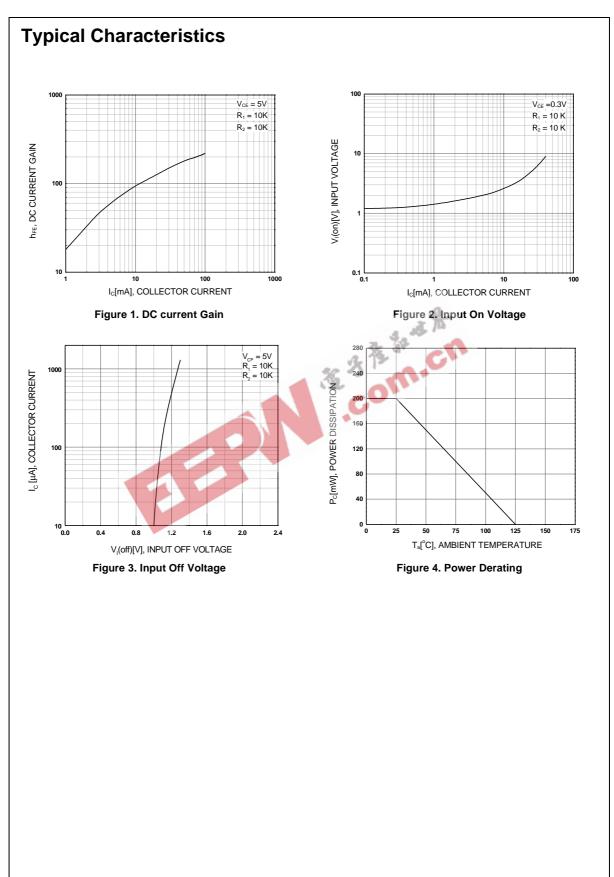
Absolute Maximum Ratings T_a=25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|------------------|-----------------------------|-----------|-------|
| V _{CBO} | Collector-Base Voltage | 50 | V |
| V _{CEO} | Collector-Emitter Voltage | 50 | V |
| V _{EBO} | Emitter-Base Voltage | 10 | V |
| I _C | Collector Current | 100 | mA |
| P _C | Collector Power Dissipation | 200 | mW |
| T _J | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | -55 ~ 150 | °C |

Electrical Characteristics T_a=25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|--------------------------------|--------------------------------------|---|------|------|------|-------|
| BV _{CBO} | Collector-Base Breakdown Voltage | I _C =10μA, I _E =0 | 50 | | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | I _C =100μA, I _B =0 | 50 | | | V |
| I _{CBO} | Collector Cut-off Current | V_{CB} =40V, I_E =0 | | | 0.1 | μΑ |
| h _{FE} | DC Current Gain | V_{CE} =5V, I_{C} =5mA | 30 | | | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C =10mA, I _B =0.5mA | | | 0.3 | V |
| f _T | Current Gain Bandwidth Product | V _{CE} =10V, I _C =5mA | | 250 | | MHz |
| C _{ob} | Output Capacitance | V _{CB} =10V, I _E =0 f=1.0MHz | | 3.7 | | pF |
| V _I (off) | Input Off Voltage | V _{CE} =5V, I _C =100μA | 0.5 | | | V |
| V _I (on) | Input On Voltage | V_{CE} =0.3V, I_{C} =10mA | | | 3 | V |
| R ₁ | Input Resistor | | 7 | 10 | 13 | ΚΩ |
| R ₁ /R ₂ | Resistor Ratio | | 0.9 | 1 | 1.1 | |

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Package Dimensions SOT-23 0.20 MIN 0.45~0.60 $0.4\underline{0} \pm 0.03$ 1.30 ±0.10 0.03~0.10 0.38 REF $0.12^{\,+0.05}_{\,-0.023}$ 0.40 ±0.03 0.96~1.14 2.90 ±0.10 0.97REF 0.95 ±0.03 0.95 ±0.03 1.90 ±0.03 0.508REF Dimensions in Millimeters

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| CROSSVOLT™ | GTO™ | POP™ | SuperSOT™-3 | |
| DOME™ | HiSeC™ | Power247™ | SuperSOT™-6 | |
| EcoSPARK™ | I^2C^{TM} | PowerTrench [®] | SuperSOT™-8 | |
| E ² CMOS™ | ISOPLANAR™ | QFET™ | SyncFET™ | |
| EnSigna™ | LittleFET™ | QS^{TM} | TinyLogic™ | |
| FACT™ | MicroFET™ | QT Optoelectronics™ | TruTranslation™ | |
| FACT Quiet series™ | MicroPak™ | Quiet Series™ | UHC™ | |
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|--------------------------|---------------------------|---|
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